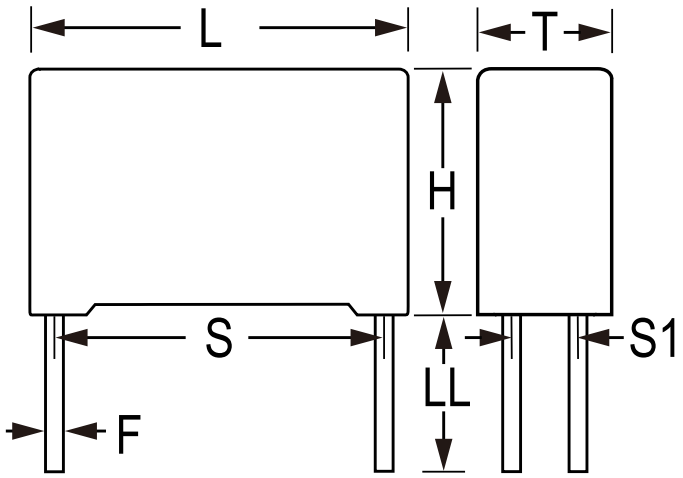
C4AF1BW5150T3LK

C4AF, Film, Metallized Polypropylene, Power, 15 uF, 10%, 500 VDC, 250 VAC, 85°C, 37.5 mm



Click here for the 3D model.

General Information	
Series	C4AF
Dielectric	Metallized Polypropylene
Style	Radial
Features	Harsh Environmental Conditions
RoHS	Yes
Lead	4 Wire Leads
Qualifications	AEC-Q200, IEC61071, EN61071, VDE0560
AEC-Q200	Yes
Typical Component Weight	74.9 g
Miscellaneous	Rth = 15 C/W.

Dimensions	
L	42mm +0.6/-0.7mm
H	45mm +0.2/-0.7mm
T	30mm +0.4/-0.7mm
S	37.5mm +/-0.4mm
S1	20.3mm +/-0.4mm
LL	6mm +0/-2mm
F	1.2mm +/-0.05mm

Packaging Specifications	
Packaging	Bulk, Box
Packaging Quantity	36

Specifications	
Capacitance	15 uF
Tolerance	10%
Voltage DC	500 VDC
Voltage AC	250 VAC
Temperature Range	-55/+105°C
Rated Temperature	85°C
Insulation Resistance	2 GOhms
Max dV/dt	27 V/us
ESR	3.4 mOhms
Ripple Current	20.8 Amps Irms (MAX), 400 Amps Ipkr
Inductance	13 nH (ESL)

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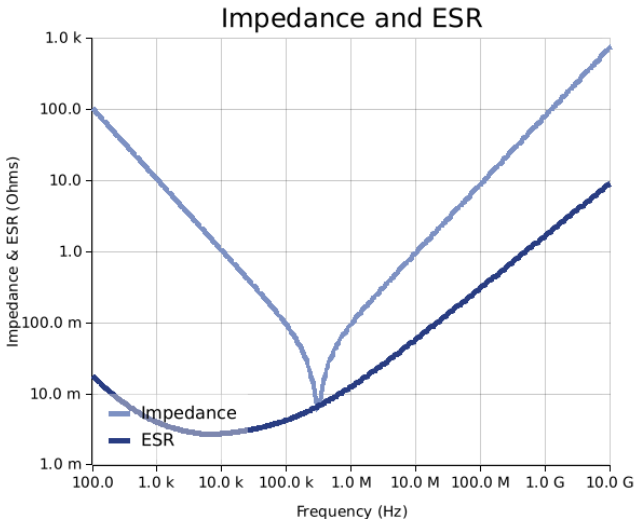
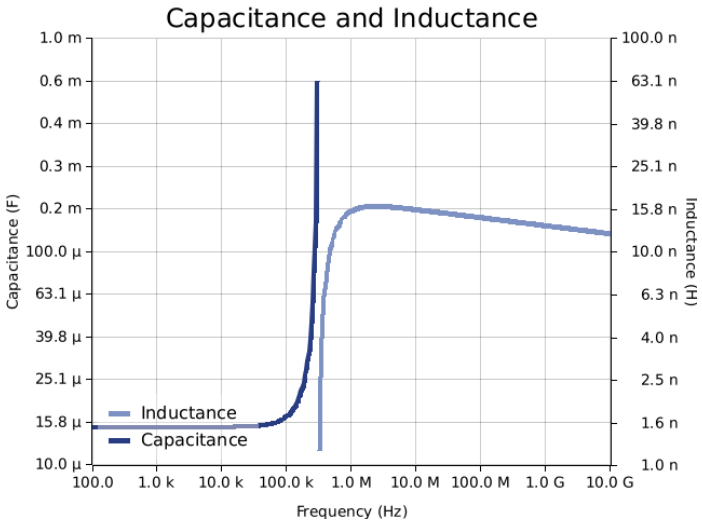
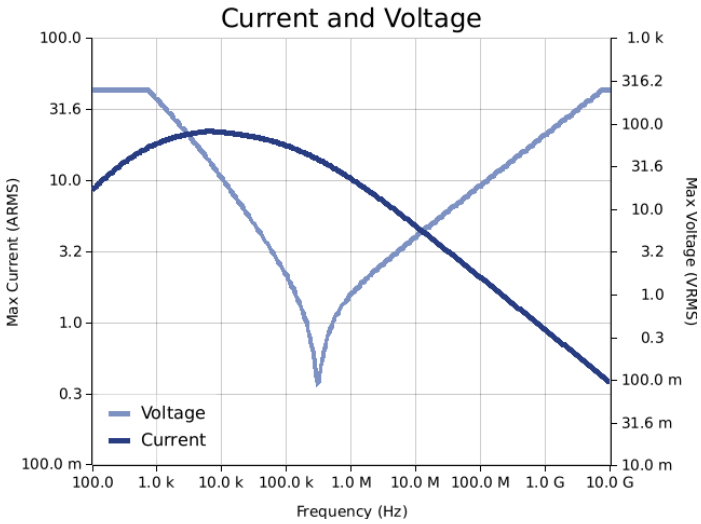
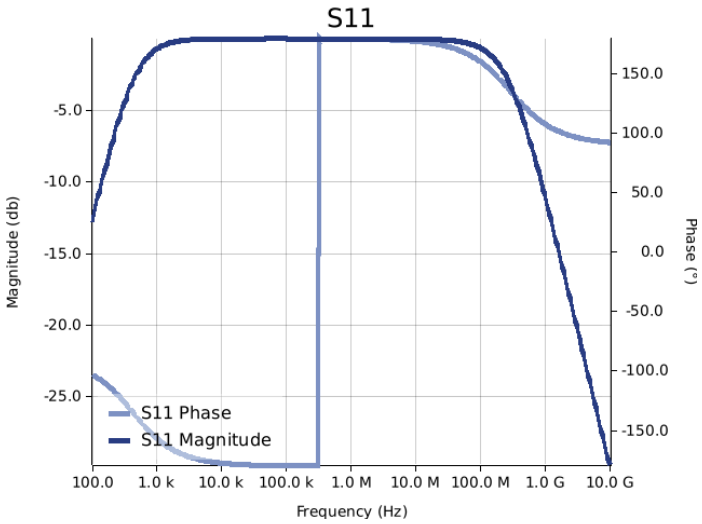
Simulations

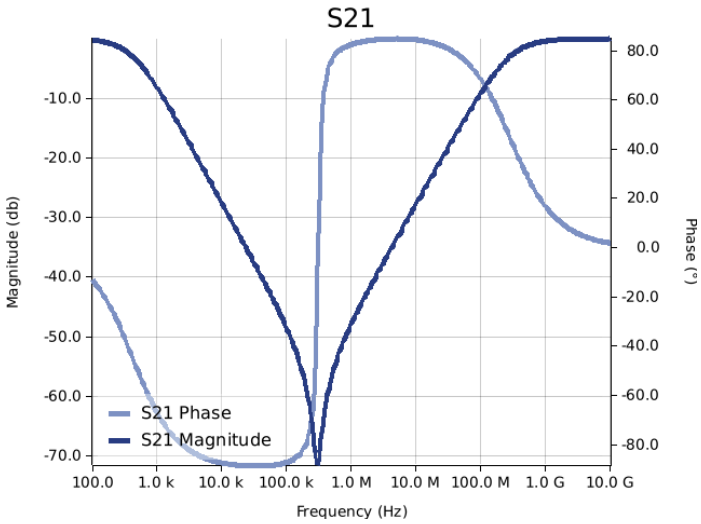
For the complete simulation environment please visit K-SIM.











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These are simulations.
This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple “Ripple Current/Voltage vs. Frequency” plots is the ESR at ambient temperature.
- The ESR in the “Temperature Rise vs. Ripple Current” plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
- The peak voltages generated in the “Temperature Rise vs. Combined Ripple Currents” plot are calculated for each frequency and are not combined with voltages generated at any other harmonics.
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the “Information”) are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.